

FAST SWITCHING NPN POWER TRANSISTOR

BUV62A

- Fast Switching Times
- Low Switching Losses
- Low Saturation Voltage
- Hermetic TO3 Metal package.
- Ideally suited for Motor Control, Switching and Linear Applications
- High Reliability Screening Options Available



ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$ unless otherwise stated)

V_{CEV}	Collector – Emitter Voltage	$V_{BE} = -1.5\text{V}$	400V
V_{CEO}	Collector – Emitter Voltage		300V
V_{EBO}	Emitter – Base Voltage		7V
I_C	Continuous Collector Current		40A
I_{CM}	Peak Collector Current		60A
I_B	Base Current		8A
I_{BM}	Base Peak Current		12A
P_D	Total Power Dissipation at	$T_C = 25^\circ\text{C}$	250W
		Derate Above 25°C	1.43W/ $^\circ\text{C}$
T_J	Junction Temperature Range		-55 to $+200^\circ\text{C}$
T_{stg}	Storage Temperature Range		-65 to $+200^\circ\text{C}$

THERMAL PROPERTIES

Symbols	Parameters	Min.	Typ.	Max.	Units
$R_{\theta JC}$	Thermal Resistance, Junction To Case			0.70	$^\circ\text{C/W}$

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ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise stated)

Symbols	Parameters	Test Conditions	Min.	Typ.	Max.	Units
$V_{(BR)CEO}^{(1)}$	Collector-Emitter Breakdown Voltage	$I_C = 10\text{mA}$ $I_B = 0$	300			V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 50\text{mA}$ $I_C = 0$	7			
I_{CEX}	Collector Cut-Off Current	$V_{CE} = 400\text{V}$ $V_{BE} = -1.5\text{V}$ $T_j = 100^\circ\text{C}$			1.0 4.0	mA
I_{CER}	Collector Cut-Off Current	$V_{CE} = 400\text{V}$ $R_{BE} = 10\Omega$ $T_j = 100^\circ\text{C}$			1.0 5.0	
I_{EBO}	Emitter Cut-Off Current	$V_{EB} = 5\text{V}$ $I_C = 0$			1.0	
$V_{CE(sat)}^{(1)}$	Collector-Emitter Saturation Voltage	$I_C = 15\text{A}$ $I_B = 1.5\text{A}$ $T_j = 100^\circ\text{C}$			0.9 1.9	V
$V_{BE(sat)}^{(1)}$	Base-Emitter Saturation Voltage	$I_C = 15\text{A}$ $I_B = 1.5\text{A}$ $T_j = 100^\circ\text{C}$			1.3 1.3	

Notes

(1) Pulse Width $\leq 300\mu\text{s}$, $\delta \leq 2\%$

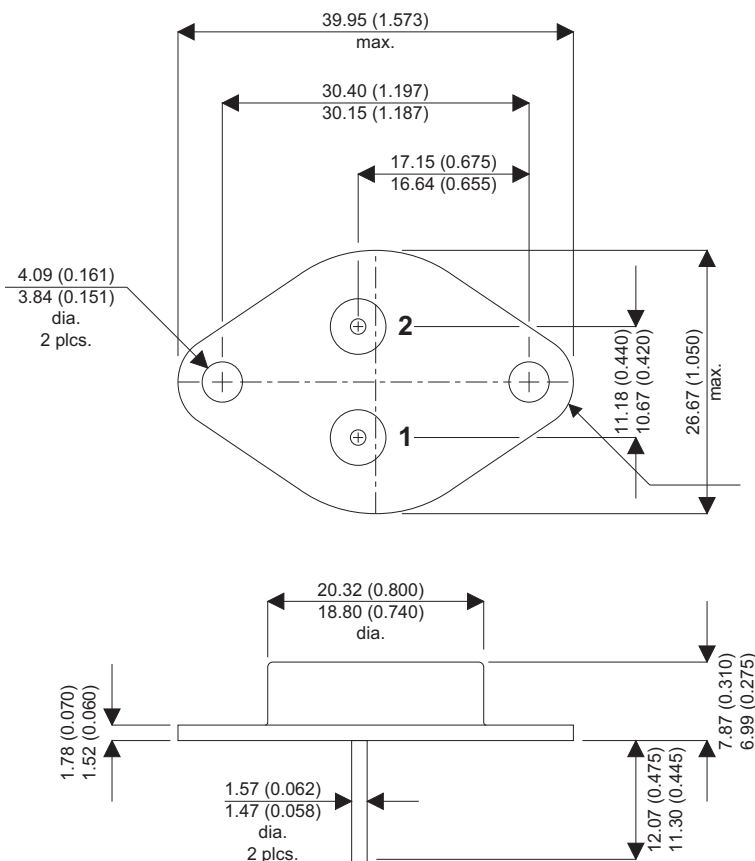
DYNAMIC CHARACTERISTICS (Inductive Load)

Symbols	Parameters	Test Conditions	Min.	Typ.	Max.	Units
t_s	Storage Time	$V_{CC} = 250\text{V}$ $V_{\text{clamp}} = 300\text{V}$		2.2		μs
t_f	Fall Time	$I_C = 15\text{A}$ $I_B = 1.5\text{A}$ $V_{BB} = -5\text{V}$ $R_{B2} = 1.6\Omega$		0.2		
t_c	Crossover Time	$L_C = 0.83\text{mH}$ $T_j = 100^\circ\text{C}$		0.3		
V_{CEW}	Maximum Collector Emitter Voltage without Snubber	$V_{CC} = 50\text{V}$ $I_{CW\text{off}} = 22\text{A}$ $V_{BB} = -5\text{V}$ $I_{B1} = 1.5\text{A}$ $L_C = 0.83\text{mH}$ $R_{BB} = 1.6\Omega$ $T_j = 125^\circ\text{C}$	300			V

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MECHANICAL DATA

Dimensions in mm (inches)



TO3 (TO-204AE)

Pin 1 - Base

Pin 2 - Emitter

Case - Collector